# RENESAS

# LOW PHASE NOISE ZERO DELAY BUFFER AND MULTIPLIER

## ICS670-01

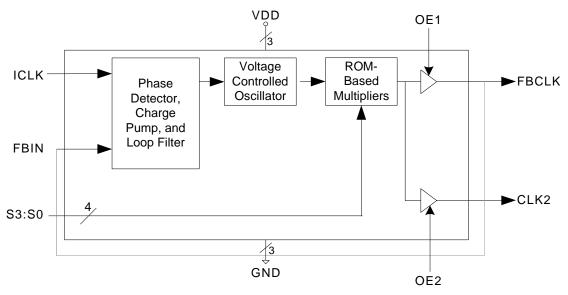
## Description

The ICS670-01 is a high-speed, low phase noise, Zero Delay Buffer (ZDB) which integrates IDT's proprietary analog/digital Phase Locked Loop (PLL) techniques. The zero delay feature means that the rising edge of the input clock aligns with the rising edges of the outputs. There are two identical outputs on the chip. FBCLK should be connected to FBIN. Each output has its own output enable pin.

The ICS670-01 is ideal for synchronizing outputs in a large variety of systems, from personal computers to data communications to video. By allowing off-chip feedback paths, the ICS670-01 can eliminate the delay through other devices. The 15 different on-chip multipliers work in a variety of applications. Arbitrary multiplication factors (including fractions) can be configured on the ICS527.

#### **Features**

- Packaged in 16-pin SOIC
- Pb (lead) free package, RoHS compliant
- Clock inputs from 5 to 160 MHz (see page 2)
- Patented PLL with low phase noise
- Output clocks up to 160 MHz at 3.3 V
- 15 selectable on-chip multipliers
- Power down mode available
- Low phase noise: -124 dBc/Hz at 10 kHz
- Output enable function tri-states outputs
- Low jitter–15 ps one sigma
- Full swing CMOS outputs with 25 mA drive capability at TTL levels
- Advanced, low power, sub-micron CMOS process
- Industrial temperature version available
- Operating voltage of 3.3 V or 5 V



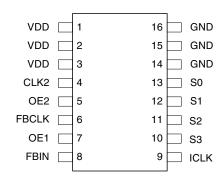
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External Feedback from FBCLK is recommended.

# **Block Diagram**

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# **Pin Assignment**



# **Multiplier Select Table**

S3	S2	S1	S0	CLK2 (and FBCLK)	Input Range (MHz)
0	0	0	0	Low (Power down entire chip)	-
0	0	0	1	Input x1.333	18 - 120
0	0	1	0	Input x6	5 - 26.67
0	0	1	1	Input x1.5	16.67 - 107
0	1	0	0	Input x3.333	7.5 - 48
0	1	0	1	Input x2.50	10 - 64
0	1	1	0	Input x4	6 - 40
0	1	1	1	Input x1	25 - 160
1	0	0	0	Input x2.333	11 - 69
1	0	0	1	Input x2.666	10 - 60
1	0	1	0	Input x12	5 - 13.33
1	0	1	1	Input x3	8 - 53.33
1	1	0	0	Input x10	5 - 16
1	1	0	1	Input x5	6 - 32
1	1	1	0	Input x8	5 - 20
1	1	1	1	Input x2	12 - 80

# **Pin Descriptions**

Pin Number	Pin Name	Pin Type	Pin Description
1 - 3	VDD	Input	Power supply. Connect all pins to the same voltage (either 3.3 V or 5 V). Pins 1 and 2 supply the analog sections of the chip.
4	CLK2	Output	Clock output from VCO. Output frequency equals the input frequency times multiplier.
5	OE2	Input	Output clock enable 2. Tri-states the clock 2 output when low.
6	FBCLK	Output	Clock output from VCO. Output frequency equals the input frequency times multiplier.
7	OE1	Input	Output clock enable 1. Tri-states the feedback clock output when low.
8	FBIN	Input	Feedback clock input.
9	ICLK	Input	Clock input. Connect to a 5 - 210 MHz clock.
10	S3	Input	Multiplier select pin 3. Determines outputs per table above. Internal pull-up.
11	S2	Input	Multiplier select pin 2. Determines outputs per table above. Internal pull-up.
12	S1	Input	Multiplier select pin 1. Determines outputs per table above. Internal pull-up.
13	S0	Input	Multiplier select pin 0. Determines outputs per table above. Internal pull-up.
14 - 16	GND	Power	Connect to ground.

## **External Components**

The ICS670-01 requires a minimum number of external components for proper operation. Decoupling capacitors of  $0.01\mu$ F should be connected from each VDD pin to the ground plane, as close to the device as possible. A series termination resistor of  $33\Omega$  should be used to each clock output pin.

## **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the ICS670-01. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDD	7 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Ambient Operating Temperature	0 to +70°C
Ambient Operating Temperature, ICS670-011	-40 to +85°C
Storage Temperature	-65 to +150°C
Junction Temperature	125°C
Soldering Temperature	260°C

## **Recommended Operation Conditions**

Parameter	Min.	Тур.	Max.	Units
Ambient Operating Temperature	0		+70	°C
Power Supply Voltage (measured in respect to GND)	+3.0		+5.5	V

## **DC Electrical Characteristics**

VDD=3.3V ±10%, Ambient temperature -40 to +85°C, unless stated otherwise

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Operating Voltage	VDD		3.0		5.5	V
Input High Voltage	V <sub>IH</sub>		2			V
Input Low Voltage	V <sub>IL</sub>				0.8	V
Output High Voltage	V <sub>OH</sub>	I <sub>OH</sub> = -12 mA	2.4			V
Output Low Voltage	V <sub>OL</sub>	I <sub>OL</sub> = 12 mA			0.4	V
Output High Voltage, CMOS level	V <sub>OH</sub>	I <sub>OH</sub> = -4 mA	VDD-0.4			V
Operating Supply Current	IDD	No Load		35		mA
Short Circuit Current	I <sub>OS</sub>	Each output		±50		mA
Internal Pull-up Resistor	R <sub>PU</sub>	OE, select pins		200		kΩ
Input Capacitance	C <sub>IN</sub>	OE, select pins		5		pF

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# **AC Electrical Characteristics**

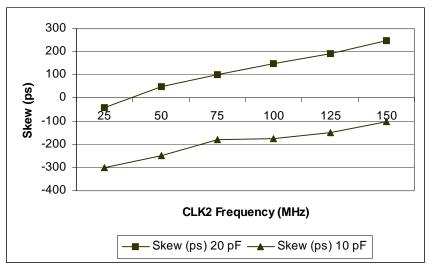
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input Clock Frequency	f <sub>IN</sub>	See table on page 2	5		160	MHz
Output Clock Frequency					160	MHz
PLL Stabilization Time	t <sub>STAB</sub>	Input frequency 5 MHz to 160 MHz		4	10	μs
Output Rise Time	t <sub>OR</sub>	0.8 to 2.0 V, no load			1.5	ns
Output Fall Time	t <sub>OF</sub>	2.0 to 0.8 V, no load			1.5	ns
Output Clock Duty Cycle	t <sub>DC</sub>	measured at VDD/2	45	50	55	%
Input to Output Skew		Note 1		±100		ps
Maximum Absolute Jitter		short term		±45		ps
Maximum Jitter		one sigma		15		ps
Phase Noise, relative to		100 Hz offset		-110		dBc/Hz
carrier, 125 MHz (x5)		1 kHz offset		-122		dBc/Hz
		10 kHz		-124		dBc/Hz
		200 kHz		-117		dBc/Hz

VDD =  $3.3V \pm 10\%$ , Ambient Temperature -40 to +85°C, unless stated otherwise

Note 1: Rising edge of ICLK compared with rising edge of CLK2, with FBCLK connected to FBIN, and 15 pF load on CLK2. See graph on page 5 for skew vs. frequency and loading.

### **Thermal Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	$\theta_{JA}$	Still air		120		°C/W
Ambient	$\theta_{JA}$	1 m/s air flow		115		°C/W
	$\theta_{JA}$	3 m/s air flow		105		°C/W
Thermal Resistance Junction to Case	θJC			58		°C/W



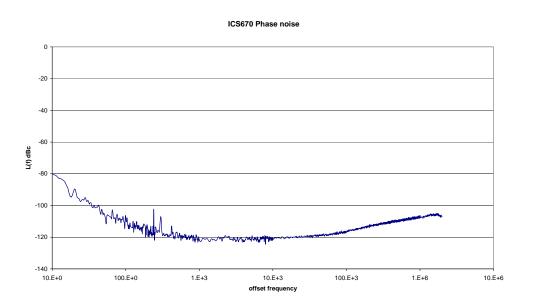
#### Figure 1. Skew from ICLK to CLK2, with change in load capacitance (VDD = 3.3V)

#### Adjusting Input/Output Skew

The data in Figure 1 can be used to adjust individual circuit characteristics and achieve the minimum possible skew between ICLK and CLK2. With a 125 MHz output, for example, having a total load capacitance of 15 pF will result in nearly zero skew between ICLK and CLK2. Note that the load

capacitance includes board trace capacitance, input capacitance of the load being driven by the ICS670-01, and any additional capacitors connected to CLK2.

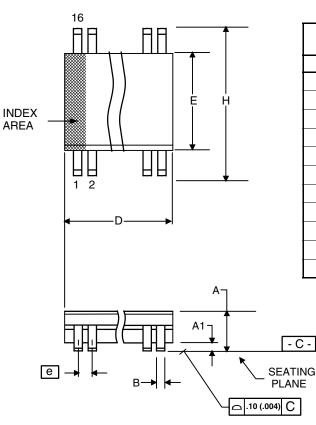
#### Figure 2. Phase Noise for 125 MHz output, 25 MHz clock input (VDD = 3.3V)



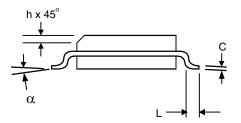
IDT® LOW PHASE NOISE ZERO DELAY BUFFER AND MULTIPLIER

# Package Outline and Package Dimensions (16-pin SOIC, 150 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



	Millimeters		Inc	hes
Symbol	Min	Мах	Min	Max
А	1.35	1.75	.0532	.0688
A1	0.10	0.25	.0040	.0098
В	0.33	0.51	.013	.020
С	0.19	0.25	.0075	.0098
D	9.80	10.00	.3859	.3937
E	3.80	4.00	.1497	.1574
е	1.27 E	BASIC	0.050	BASIC
Н	5.80	6.20	.2284	.2440
h	0.25	0.50	.010	.020
L	0.40	1.27	.016	.050
α	0°	<b>8</b> °	0°	<b>8</b> °



## **Ordering Information**

ICS670-01

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
670M-01LF	670M-01LF	Tubes	16-pin SOIC	0 to +70° C
670M-01LFT	670M-01LF	Tape and Reel	16-pin SOIC	0 to +70° C
670M-01ILF	670M-01ILF	Tubes	16-pin SOIC	-40 to +85° C
670M-01ILFT	670M-01ILF	Tape and Reel	16-pin SOIC	-40 to +85° C

#### "LF" suffix to the part number denotes Pb-Free configuration, RoHS compliant.

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#### **Revision History**

Rev.	Date	Originator	Description of Change
L	01/23/15	RDW	Updated AC characterization table with new parameter "PLL Stabilization Time".

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